

Features

- **Operating Frequency Range**
 - Up to 18MHz (Typ) at $V_{CC} = 5V$
 - Minimum Center Frequency of 12MHz at $V_{CC} = 4.5V$
- **Choice of Three Phase Comparators**
 - EXCLUSIVE-OR
 - Edge-Triggered JK Flip-Flop
 - Edge-Triggered RS Flip-Flop
- **Excellent VCO Frequency Linearity**
- **VCO-Inhibit Control for ON/OFF Keying and for Low Standby Power Consumption**
- **Minimal Frequency Drift**
- **Operating Power Supply Voltage Range**
 - VCO Section 3V to 6V
 - Digital Section 2V to 6V
- **Fanout (Over Temperature Range)**
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- **Wide Operating Temperature Range ... -55°C to 125°C**
- **Balanced Propagation Delay and Transition Times**
- **Significant Power Reduction Compared to LSTTL Logic ICs**
- **HC Types**
 - 2V to 6V Operation
 - High Noise Immunity: $N_{IL} = 30\%$, $N_{IH} = 30\%$ of V_{CC} at $V_{CC} = 5V$
- **HCT Types**
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, $V_{IL} = 0.8V$ (Max), $V_{IH} = 2V$ (Min)
 - CMOS Input Compatibility, $I_I \leq 1\mu A$ at VOL, VOH

Applications

- FM Modulation and Demodulation
- Frequency Synthesis and Multiplication
- Frequency Discrimination
- Tone Decoding
- Data Synchronization and Conditioning
- Voltage-to-Frequency Conversion
- Motor-Speed Control

Description

The 'HC4046A and 'HCT4046A are high-speed silicon-gate CMOS devices that are pin compatible with the CD4046B of the "4000B" series. They are specified in compliance with JEDEC standard number 7.

The 'HC4046A and 'HCT4046A are phase-locked-loop circuits that contain a linear voltage-controlled oscillator (VCO) and three different phase comparators (PC1, PC2 and PC3). A signal input and a comparator input are common to each comparator.

The signal input can be directly coupled to large voltage signals, or indirectly coupled (with a series capacitor) to small voltage signals. A self-bias input circuit keeps small voltage signals within the linear region of the input amplifiers. With a passive low-pass filter, the 4046A forms a second-order loop PLL. The excellent VCO linearity is achieved by the use of linear op-amp techniques.

Ordering Information

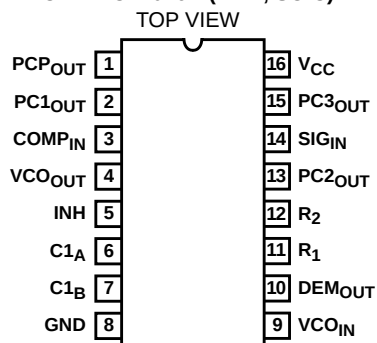
PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4046AF3A	-55 to 125	16 Ld Cerdip
CD54HCT4046AF3A	-55 to 125	16 Ld Cerdip
CD74HC4046AE	-55 to 125	16 Ld PDIP
CD74HC4046AM	-55 to 125	16 Ld SOIC
CD74HC4046AMT	-55 to 125	16 Ld SOIC
CD74HC4046AM96	-55 to 125	16 Ld SOIC
CD74HC4046ANSR	-55 to 125	16 Ld SOP
CD74HC4046APWR	-55 to 125	16 Ld TSSOP
CD74HC4046APWT	-55 to 125	16 Ld TSSOP
CD74HCT4046AE	-55 to 125	16 Ld PDIP
CD74HCT4046AM	-55 to 125	16 Ld SOIC
CD74HCT4046AMT	-55 to 125	16 Ld SOIC
CD74HCT4046AM96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

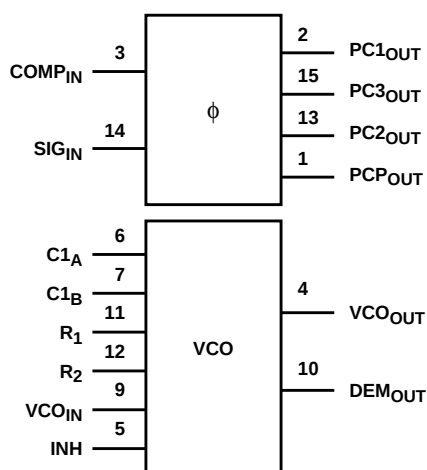
CD54HC4046A, CD74HC4046A, CD54HCT4046A, CD74HCT4046A

Pinout

CD54HC4046A, CD54HCT4046A (CERDIP)
 CD74HC4046A (PDIP, SOIC, SOP, TSSOP)
 CD74HCT4046A (PDIP, SOIC)



Functional Diagram



Pin Descriptions

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	PCP _{OUT}	Phase Comparator Pulse Output
2	PC1 _{OUT}	Phase Comparator 1 Output
3	COMP _{IN}	Comparator Input
4	VCO _{OUT}	VCO Output
5	INH	Inhibit Input
6	C1 _A	Capacitor C1 Connection A
7	C1 _B	Capacitor C1 Connection B
8	GND	Ground (0V)
9	VCO _{IN}	VCO Input
10	DEM _{OUT}	Demodulator Output
11	R ₁	Resistor R1 Connection
12	R ₂	Resistor R2 Connection
13	PC2 _{OUT}	Phase Comparator 2 Output
14	SIG _{IN}	Signal Input
15	PC3 _{OUT}	Phase Comparator 3 Output
16	V _{CC}	Positive Supply Voltage

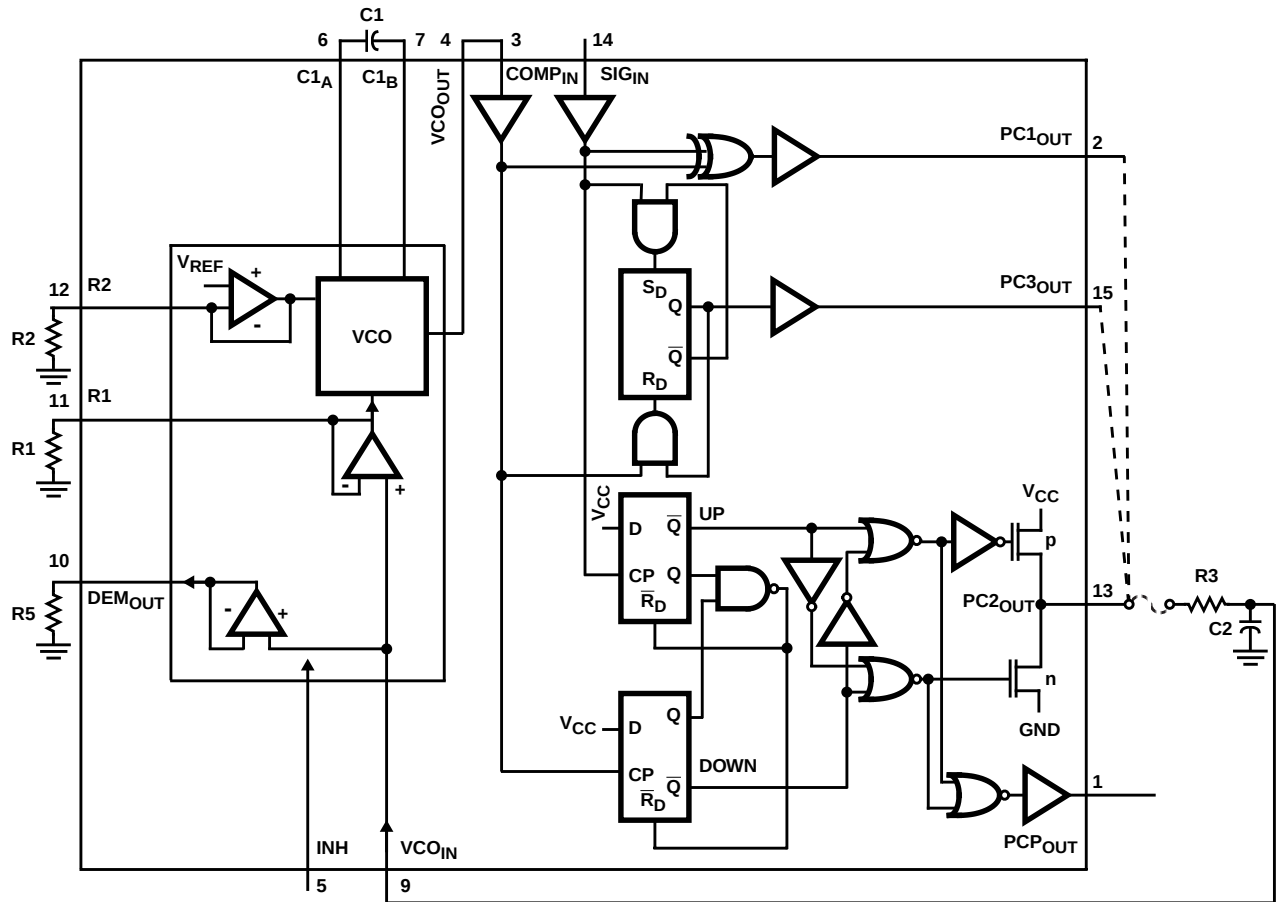


FIGURE 1. LOGIC DIAGRAM

General Description

VCO

The VCO requires one external capacitor C1 (between C1_A and C1_B) and one external resistor R1 (between R₁ and GND) or two external resistors R1 and R2 (between R₁ and GND, and R₂ and GND). Resistor R1 and capacitor C1 determine the frequency range of the VCO. Resistor R2 enables the VCO to have a frequency offset if required. See logic diagram, Figure 1.

The high input impedance of the VCO simplifies the design of low-pass filters by giving the designer a wide choice of resistor/capacitor ranges. In order not to load the low-pass filter, a demodulator output of the VCO input voltage is provided at pin 10 (DEM_{OUT}). In contrast to conventional techniques where the DEM_{OUT} voltage is one threshold voltage lower than the VCO input voltage, here the DEM_{OUT} voltage equals that of the VCO input. If DEM_{OUT} is used, a load resistor (R_S) should be connected from DEM_{OUT} to GND; if unused, DEM_{OUT} should be left open. The VCO output (VCO_{OUT}) can be connected directly to the comparator input (COMP_{IN}), or connected via a frequency-divider. The VCO output signal has a specified duty factor of 50%. A LOW level at the inhibit input (INH) enables the VCO and demodulator, while a HIGH level turns both off to minimize standby power consumption.

Phase Comparators

The signal input (SIG_{IN}) can be directly coupled to the self-biasing amplifier at pin 14, provided that the signal swing is between the standard HC family input logic levels. Capacitive coupling is required for signals with smaller swings.

Phase Comparator 1 (PC1)

This is an Exclusive-OR network. The signal and comparator input frequencies (f_i) must have a 50% duty factor to obtain the maximum locking range. The transfer characteristic of PC1, assuming ripple (f_r = 2f_i) is suppressed, is:

$V_{\text{DEMOUT}} = (V_{\text{CC}}/\pi) (\phi_{\text{SIGIN}} - \phi_{\text{COMPIN}})$ where V_{DEMOUT} is the demodulator output at pin 10; V_{DEMOUT} = V_{PC1OUT} (via low-pass filter).

The average output voltage from PC1, fed to the VCO input via the low-pass filter and seen at the demodulator output at pin 10 (V_{DEMOUT}), is the resultant of the phase differences of signals (SIG_{IN}) and the comparator input (COMP_{IN}) as shown in Figure 2. The average of V_{DEM} is equal to 1/2 V_{CC} when there is no signal or noise at SIG_{IN}, and with this input the VCO oscillates at the center frequency (f₀). Typical waveforms for the PC1 loop locked at f₀ are shown in Figure 3.

The frequency capture range ($2f_C$) is defined as the frequency range of input signals on which the PLL will lock if it was initially out-of-lock. The frequency lock range ($2f_L$) is defined as the frequency range of input signals on which the loop will stay locked if it was initially in lock. The capture range is smaller or equal to the lock range.

With PC1, the capture range depends on the low-pass filter characteristics and can be made as large as the lock range. This configuration retains lock behavior even with very noisy input signals. Typical of this type of phase comparator is that it can lock to input frequencies close to the harmonics of the VCO center frequency.

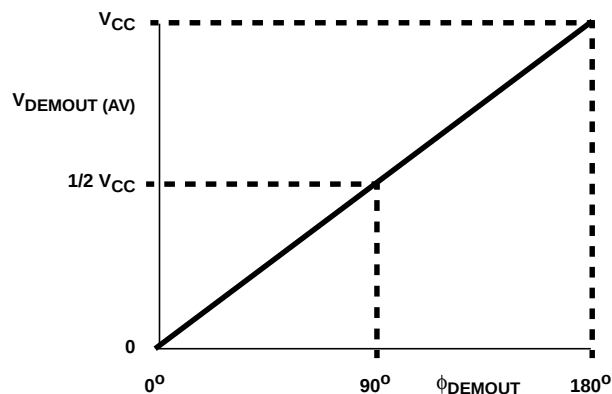


FIGURE 2. PHASE COMPARATOR 1: AVERAGE OUTPUT VOLTAGE vs INPUT PHASE DIFFERENCE:
 $V_{DEMOUT} = V_{PC1OUT} = (V_{CC}/\pi) (\phi_{SIGIN} - \phi_{COMPIN})$; $\phi_{DEMOUT} = (\phi_{SIGIN} - \phi_{COMPIN})$

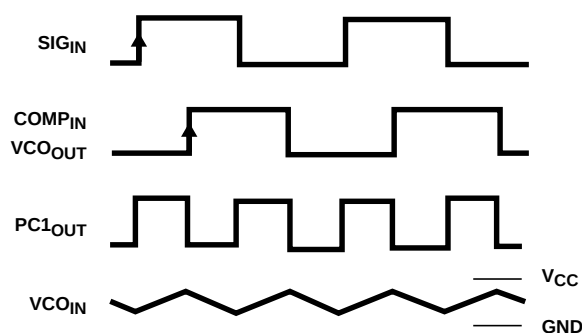


FIGURE 3. TYPICAL WAVEFORMS FOR PLL USING PHASE COMPARATOR 1, LOOP LOCKED AT f_0

Phase Comparator 2 (PC2)

This is a positive edge-triggered phase and frequency detector. When the PLL is using this comparator, the loop is controlled by positive signal transitions and the duty factors of SIG_{IN} and $COMP_{IN}$ are not important. PC2 comprises two D-type flip-flops, control-gating and a three-state output stage. The circuit functions as an up-down counter (Figure 1) where SIG_{IN} causes an up-count and $COMP_{IN}$ a down-count. The transfer function of PC2, assuming ripple ($f_r = f_i$) is suppressed, is:

$V_{DEMOUT} = (V_{CC}/4\pi) (\phi_{SIGIN} - \phi_{COMPIN})$ where V_{DEMOUT} is the demodulator output at pin 10; $V_{DEMOUT} = V_{PC2OUT}$ (via low-pass filter).

The average output voltage from PC2, fed to the VCO via the low-pass filter and seen at the demodulator output at pin 10 (V_{DEMOUT}), is the resultant of the phase differences of SIG_{IN} and $COMP_{IN}$ as shown in Figure 4. Typical waveforms for the PC2 loop locked at f_0 are shown in Figure 5.

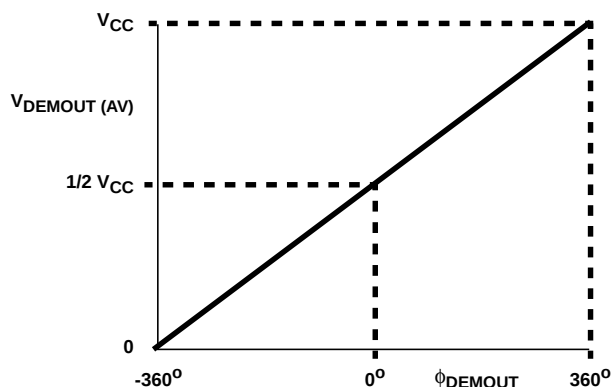


FIGURE 4. PHASE COMPARATOR 2: AVERAGE OUTPUT VOLTAGE vs INPUT PHASE DIFFERENCE:

$$V_{DEMOUT} = V_{PC2OUT} = (V_{CC}/4\pi) (\phi_{SIGIN} - \phi_{COMPIN});$$

$$\phi_{DEMOUT} = (\phi_{SIGIN} - \phi_{COMPIN})$$

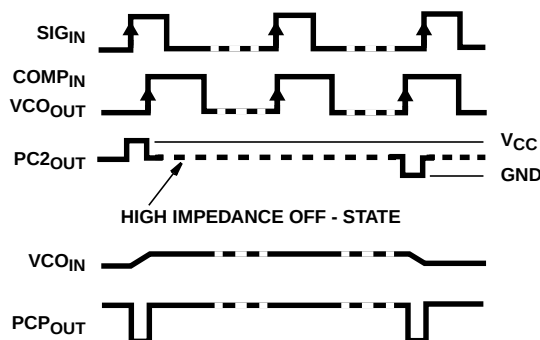


FIGURE 5. TYPICAL WAVEFORMS FOR PLL USING PHASE COMPARATOR 2, LOOP LOCKED AT f_0

When the frequencies of SIG_{IN} and $COMP_{IN}$ are equal but the phase of SIG_{IN} leads that of $COMP_{IN}$, the p-type output driver at $PC2_{OUT}$ is held "ON" for a time corresponding to the phase difference (ϕ_{DEMOUT}). When the phase of SIG_{IN} lags that of $COMP_{IN}$, the n-type driver is held "ON".

When the frequency of SIG_{IN} is higher than that of $COMP_{IN}$, the p-type output driver is held "ON" for most of the input signal cycle time, and for the remainder of the cycle both n- and p-type drivers are "OFF" (three-state). If the SIG_{IN} frequency is lower than the $COMP_{IN}$ frequency, then it is the n-type driver that is held "ON" for most of the cycle. Subsequently, the voltage at the capacitor (C_2) of the low-pass filter connected to $PC2_{OUT}$ varies until the signal and comparator inputs are equal in both phase and

frequency. At this stable point the voltage on C2 remains constant as the PC2 output is in three-state and the VCO input at pin 9 is a high impedance. Also in this condition, the signal at the phase comparator pulse output (PCP_{OUT}) is a HIGH level and so can be used for indicating a locked condition.

Thus, for PC2, no phase difference exists between SIG_{IN} and COMP_{IN} over the full frequency range of the VCO. Moreover, the power dissipation due to the low-pass filter is reduced because both p- and n-type drivers are "OFF" for most of the signal input cycle. It should be noted that the PLL lock range for this type of phase comparator is equal to the capture range and is independent of the low-pass filter. With no signal present at SIG_{IN}, the VCO adjusts, via PC2, to its lowest frequency.

Phase Comparator 3 (PC3)

This is a positive edge-triggered sequential phase detector using an RS-type flip-flop. When the PLL is using this comparator, the loop is controlled by positive signal transitions and the duty factors of SIG_{IN} and COMP_{IN} are not important. The transfer characteristic of PC3, assuming ripple ($f_r = f_i$) is suppressed, is:

$V_{\text{DEMOUT}} = (V_{\text{CC}}/2\pi) (f_{\text{SIGIN}} - f_{\text{COMPIN}})$ where V_{DEMOUT} is the demodulator output at pin 10; $V_{\text{DEMOUT}} = V_{\text{PC3OUT}}$ (via low-pass filter).

The average output from PC3, fed to the VCO via the low-pass filter and seen at the demodulator at pin 10 (V_{DEMOUT}), is the resultant of the phase differences of SIG_{IN} and COMP_{IN} as shown in Figure 6. Typical waveforms for the PC3 loop locked at f_0 are shown in Figure 7.

The phase-to-output response characteristic of PC3 (Figure 6) differs from that of PC2 in that the phase angle between SIG_{IN} and COMP_{IN} varies between 0° and 360° and is 180° at the center frequency. Also PC3 gives a greater voltage swing than PC2 for input phase differences but as a consequence the ripple content of the VCO input signal is higher. With no signal present at SIG_{IN}, the VCO adjusts, via PC3, to its highest frequency.

The only difference between the HC and HCT versions is the input level specification of the INH input. This input disables the VCO section. The comparator's sections are identical, so that there is no difference in the SIG_{IN} (pin 14) or COMP_{IN} (pin 3) inputs between the HC and the HCT versions.

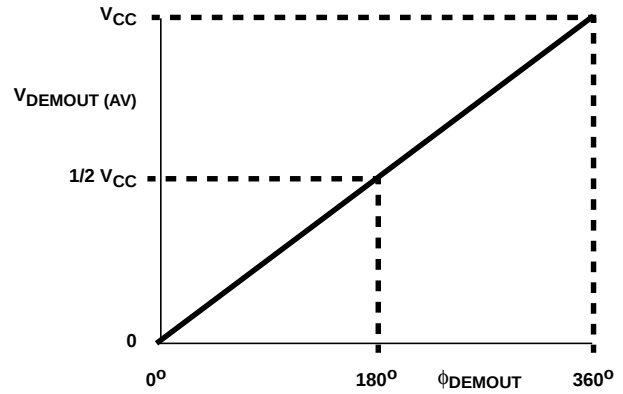


FIGURE 6. PHASE COMPARATOR 3: AVERAGE OUTPUT VOLTAGE vs INPUT PHASE DIFFERENCE:

$$\begin{aligned} V_{\text{DEMOUT}} &= V_{\text{PC3OUT}} \\ &= (V_{\text{CC}}/2\pi) (\phi_{\text{SIGIN}} - \phi_{\text{COMPIN}}); \\ \phi_{\text{DEMOUT}} &= (\phi_{\text{SIGIN}} - \phi_{\text{COMPIN}}) \end{aligned}$$

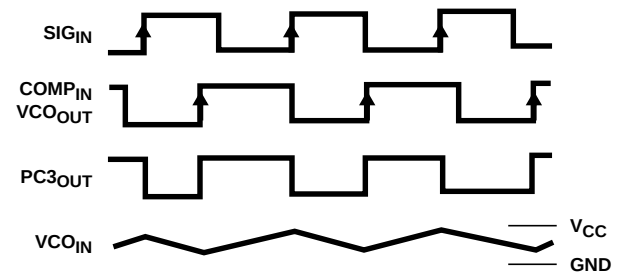


FIGURE 7. TYPICAL WAVEFORMS FOR PLL USING PHASE COMPARATOR 3, LOOP LOCKED AT f_0

CD54HC4046A, CD74HC4046A, CD54HCT4046A, CD74HCT4046A

Absolute Maximum Ratings

DC Supply Voltage, V_{CC}	-0.5V to 7V
DC Input Diode Current, I_{IK}	
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$	$\pm 20mA$
DC Output Diode Current, I_{OK}	
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	$\pm 20mA$
DC Drain Current, per Output, I_O	
For $-0.5V < V_O < V_{CC} + 0.5V$	$\pm 25mA$
DC Output Source or Sink Current per Output Pin, I_O	
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$	$\pm 25mA$
DC V_{CC} or Ground Current, I_{CC}	$\pm 50mA$

Thermal Information

Package Thermal Impedance, θ_{JA} (see Note 1):	
E (PDIP) Package	67°C/W
M (SOIC) Package	73°C/W
NS (SOP) Package	64°C/W
PW (TSSOP) Package	108°C/W
Maximum Junction Temperature	150°C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range, T_A	-55°C to 125°C
Supply Voltage Range, V_{CC}	
HC Types	.2V to 6V
HCT Types	.4.5V to 5.5V
DC Input or Output Voltage, V_I, V_O	0V to V_{CC}
Input Rise and Fall Time	
2V	1000ns (Max)
4.5V	500ns (Max)
6V	400ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS		V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V _I (V)	I _O (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES												
VCO SECTION												
INH High Level Input Voltage	V _{IH}	-	-	3	2.1	-	-	2.1	-	2.1	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
INH Low Level Input Voltage	V _{IL}	-	-	3	-	-	0.9	-	0.9	-	0.9	V
				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
VCO _{OUT} High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	3	2.9	-	-	2.9	-	2.9	-	V
			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
VCO _{OUT} High Level Output Voltage TTL Loads	V _{OH}	V _{IH} or V _{IL}	-	-	-	-	-	-	-	-	-	V
			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
VCO _{OUT} Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
VCO _{OUT} Low Level Output Voltage TTL Loads	V _{OL}	V _{IH} or V _{IL}	-	-	-	-	-	-	-	-	-	V
			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
C1A, C1B Low Level Output Voltage (Test Purposes Only)	V _{OL}	V _{IL} or V _{IH}	4	4.5	-	-	0.40	-	0.47	-	0.54	V
			5.2	6	-	-	0.40	-	0.47	-	0.54	V

CD54HC4046A, CD74HC4046A, CD54HCT4046A, CD74HCT4046A

DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V _I (V)	I _O (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
INH VCO _{IN} Input Leakage Current	I _I	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
R1 Range (Note 2)	-	-	-	4.5	3	-	300	-	-	-	-	kΩ
R2 Range (Note 2)	-	-	-	4.5	3	-	300	-	-	-	-	kΩ
C1 Capacitance Range	-	-	-	3	-	-	No Limit	-	-	-	-	pF
				4.5	-	-		-	-	-	-	pF
				6	-	-		-	-	-	-	pF
VCO _{IN} Operating Voltage Range	-	Over the range specified for R1 for Linearity See Figure 10, and 34 - 37 (Note 3)	3	1.1	-	1.9	-	-	-	-	V	
			4.5	1.1	-	3.2	-	-	-	-	V	
			6	1.1	-	4.6	-	-	-	-	V	
PHASE COMPARATOR SECTION												
SIG _{IN} , COMP _{IN} DC Coupled High-Level Input Voltage	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
SIG _{IN} , COMP _{IN} DC Coupled Low-Level Input Voltage	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
PCP _{OUT} , PCn OUT High-Level Output Voltage CMOS Loads	V _{OH}	V _{IL} or V _{IH}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
				4.5	4.4	-	-	4.4	-	4.4	-	V
				6	5.9	-	-	5.9	-	5.9	-	V
PCP _{OUT} , PCn OUT High-Level Output Voltage TTL Loads	V _{OH}	V _{IL} or V _{IH}	-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
PCP _{OUT} , PCn OUT Low-Level Output Voltage CMOS Loads	V _{OL}	V _{IL} or V _{IH}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
				4.5	-	-	0.1	-	0.1	-	0.1	V
				6	-	-	0.1	-	0.1	-	0.1	V
PCP _{OUT} , PCn OUT Low-Level Output Voltage TTL Loads	V _{OL}	V _{IL} or V _{IH}	4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
SIG _{IN} , COMP _{IN} Input Leakage Current	I _I	V _{CC} or GND	-	2	-	-	±3	-	±4	-	±5	μA
				3	-	-	±7	-	±9	-	±11	μA
				4.5	-	-	±18	-	±23	-	±29	μA
				6	-	-	±30	-	±38	-	±45	μA
PC2 _{OUT} Three-State Off-State Current	I _{OZ}	V _{IL} or V _{IH}	-	6	-	-	±0.5	-	±5	-	±10	μA
SIG _{IN} , COMP _{IN} Input Resistance	R _I	V _I at Self-Bias Operation Point: ΔV _I = 0.5V, See Figure 10		3	-	800	-	-	-	-	-	kΩ
				4.5	-	250	-	-	-	-	-	kΩ
				6	-	150	-	-	-	-	-	kΩ
DEMODULATOR SECTION												
Resistor Range	R _S	at R _S > 300kΩ Leakage Current Can Influence V _{DEMOUT}		3	50	-	300	-	-	-	-	kΩ
				4.5	50	-	300	-	-	-	-	kΩ
				6	50	-	300	-	-	-	-	kΩ

CD54HC4046A, CD74HC4046A, CD54HCT4046A, CD74HCT4046A

DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS	
		V _I (V)	I _O (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX		
Offset Voltage V _{COIN} to V _{DEM}	V _{OFF}	V _I = V _{VCO IN} = $\frac{V_{CC}}{2}$ Values Taken Over R _S Range See Figure 23		3	-	±30	-	-	-	-	-	mV	
				4.5	-	±20	-	-	-	-	-	mV	
				6	-	±10	-	-	-	-	-	mV	
Dynamic Output Resistance at DEM _{OUT}	R _D	V _{DEMOUT} = $\frac{V_{CC}}{2}$		3	-	25	-	-	-	-	-	Ω	
				4.5	-	25	-	-	-	-	-	-	Ω
				6	-	25	-	-	-	-	-	-	Ω
Quiescent Device Current	I _{CC}	Pins 3, 5 and 14 at V _{CC} Pin 9 at GND, I ₁ at Pins 3 and 14 to be excluded		6	-	-	8	-	80	-	160	μA	
HCT TYPES													
VCO SECTION													
INH High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V	
INH Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V	
VCO _{OUT} High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V	
VCO _{OUT} High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V	
VCO _{OUT} Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
VCO _{OUT} Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V	
C1A, C1B Low Level Output Voltage (Test Purposes Only)	V _{OL}	V _{IH} or V _{IL}	4	4.5	-	-	0.40	-	0.47	-	0.54	V	
INH VCO _{IN} Input Leakage Current	I _I	Any Voltage Between V _{CC} and GND		5.5	-		±0.1	-	±1	-	±1	μA	
R1 Range (Note 2)	-	-	-	4.5	3	-	300	-	-	-	-	kΩ	
R2 Range (Note 2)	-	-	-	4.5	3	-	300	-	-	-	-	kΩ	
C1 Capacitance Range	-	-	-	4.5	0	-	No Limit	-	-	-	-	pF	
VCO _{IN} Operating Voltage Range	-	Over the range specified for R1 for Linearity See Figure 10, and 34 - 37 (Note 3)		4.5	1.1	-	3.2	-	-	-	-	V	
PHASE COMPARATOR SECTION													
SIG _{IN} , COMP _{IN} DC Coupled High-Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V	

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DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V _I (V)	I _O (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
SIG _{IN} , COMP _{IN} DC Coupled Low-Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
PCP _{OUT} , PCn OUT High-Level Output Voltage CMOS Loads	V _{OH}	V _{IL} or V _{IH}	-	4.5	4.4	-	-	4.4	-	4.4	-	V
PCP _{OUT} , PCn OUT High-Level Output Voltage TTL Loads	V _{OH}	V _{IL} or V _{IH}	-	4.5	3.98	-	-	3.84	-	3.7	-	V
PCP _{OUT} , PCn OUT Low-Level Output Voltage CMOS Loads	V _{OL}	V _{IL} or V _{IH}	-	4.5	-	-	0.1	-	0.1	-	0.1	V
PCP _{OUT} , PCn OUT Low-Level Output Voltage TTL Loads	V _{OL}	V _{IL} or V _{IH}	-	4.5	-	-	0.26	-	0.33	-	0.4	V
SIG _{IN} , COMP _{IN} Input Leakage Current	I _I	Any Voltage Between V _{CC} and GND	-	5.5	-	-	±30		±38		±45	μA
PC2 _{OUT} Three-State Off-State Current	I _{OZ}	V _{IL} or V _{IH}	-	5.5	-	-	±0.5	±5	-	-	±10	μA
SIG _{IN} , COMP _{IN} Input Resistance	R _I	V _I at Self-Bias Operation Point: ΔV _I = 0.5V, See Figure 10		4.5	-	250	-	-	-	-	-	kΩ
DEMODULATOR SECTION												
Resistor Range	R _S	at R _S > 300kΩ Leakage Current Can Influence V _{DEM OUT}		4.5	5	-	300	-	-	-	-	kΩ
Offset Voltage VCO _{IN} to V _{DEM}	V _{OFF}	V _I = V _{VCO IN} = $\frac{V_{CC}}{2}$ Values taken over R _S Range See Figure 23		4.5	-	±20	-	-	-	-	-	mV
Dynamic Output Resistance at DEM _{OUT}	R _D	V _{DEM OUT} = $\frac{V_{CC}}{2}$		4.5	-	25	-	-	-	-	-	Ω
Quiescent Device Current	I _{CC}	V _{CC} or GND	-	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 4)	V _{CC} -2.1 Excluding Pin 5	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

NOTES:

- The value for R1 and R2 in parallel should exceed 2.7kΩ.
- The maximum operating voltage can be as high as V_{CC} -0.9V, however, this may result in an increased offset voltage.
- For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

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HCT Input Loading Table

INPUT	UNIT LOADS
INH	1

NOTE: Unit load is ΔI_{CC} limit specific in DC Electrical Specifications Table, e.g., 360 μ A max. at 25°C.

Switching Specifications $C_L = 50$ pF, Input $t_r, t_f = 6$ ns

PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS		
				MIN	TYP	MAX	MIN	MAX	MIN	MAX			
HC TYPES													
PHASE COMPARATOR SECTION													
Propagation Delay SIG _{IN} , COMP _{IN} to PC _I OUT	t _{PLH} , t _{PHL}		2	-	-	200	-	250	-	300	ns		
			4.5	-	-	40	-	50	-	60	ns		
			6	-	-	34	-	43	-	51	ns		
SIG _{IN} , COMP _{IN} to PCP _{OUT}			2	-	-	300	-	375	-	450	ns		
			4.5	-	-	60	-	75	-	90	ns		
			6	-	-	51	-	64	-	77	ns		
SIG _{IN} , COMP _{IN} to PC3 _{OUT}			2	-	-	245	-	305	-	307	ns		
			4.5	-	-	49	-	61	-	74	ns		
			6	-	-	42	-	52	-	63	ns		
Output Transition Time	t _{THL} , t _{TLH}		2	-	-	75	-	95	-	110	ns		
			4.5	-	-	15	-	19	-	22	ns		
			6	-	-	13	-	16	-	19	ns		
Output Enable Time, SIG _{IN} , COMP _{IN} to PC2 _{OUT}	t _{PZH} , t _{PZL}		2	-	-	265	-	330	-	400	ns		
			4.5	-	-	53	-	66	-	80	ns		
			6	-	-	45	-	56	-	68	ns		
Output Disable Time, SIG _{IN} , COMP _{IN} to PC2 _{OUT}	t _{PHZ} , t _{PLZ}		2	-	-	315	-	395	-	475	ns		
			4.5	-	-	63	-	79	-	95	ns		
			6	-	-	54	-	67	-	81	ns		
AC Coupled Input Sensitivity (p-p) at SIG _{IN} or COMP _{IN}		V _{I(P-P)}	3	-	11	-	-	-	-	-	mV		
			4.5	-	15	-	-	-	-	-	-	mV	
			6	-	33	-	-	-	-	-	-	mV	
VCO SECTION													
Frequency Stability with Temperature Change	Δf ΔT	R ₁ = 100kΩ, R ₂ = ∞	3	-	0.11	-	-	-	-	-	%/°C		
			4.5	-	0.11	-	-	-	-	-	-	%/°C	
			6	-	0.11	-	-	-	-	-	-	%/°C	
Maximum Frequency	f _{MAX}	C ₁ = 50pF R ₁ = 3.5kΩ R ₂ = ∞	3	-	24	-	-	-	-	-	MHz		
			4.5	-	24	-	-	-	-	-	-	MHz	
			6	-	24	-	-	-	-	-	-	MHz	
		C ₁ = 0pF R ₁ = 9.1kΩ R ₂ = ∞	3	-	38	-	-	-	-	-	-	MHz	
			4.5	-	38	-	-	-	-	-	-	-	MHz
			6	-	38	-	-	-	-	-	-	-	MHz

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Switching Specifications $C_L = 50\text{pF}$, Input t_r , $t_f = 6\text{ns}$ (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	V _{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS			
				MIN	TYP	MAX	MIN	MAX	MIN	MAX				
Center Frequency		C ₁ = 40pF R ₁ = 3kΩ R ₂ = ∞ VCO _{IN} = VCC/2	3	7	10	-	-	-	-	-	MHz			
			4.5	12	17	-	-	-	-	-	MHz			
			6	14	21	-	-	-	-	-	MHz			
Frequency Linearity	Δf _{VCO}	R ₁ = 100kΩ R ₂ = ∞ C ₁ = 100pF	3	-	0.4	-	-	-	-	-	%			
			4.5	-	0.4	-	-	-	-	-	%			
			6	-	0.4	-	-	-	-	-	%			
Offset Frequency		R ₂ = 220kΩ C ₁ = 1nF	3	-	400	-	-	-	-	-	kHz			
			4.5	-	400	-	-	-	-	-	kHz			
			6	-	400	-	-	-	-	-	kHz			
DEMODULATOR SECTION														
V _{OUT} V _S f _{IN}		R ₁ = 100kΩ R ₂ = ∞ C ₁ = 100pF R _S = 10kΩ R ₃ = 100kΩ C ₂ = 100pF	3	-	-	-	-	-	-	-	mV/kHz			
			4.5	-	330	-	-	-	-	-	mV/kHz			
			6	-	-	-	-	-	-	-	mV/kHz			
HCT TYPES														
PHASE COMPARATOR SECTION														
Propagation Delay SIG _{IN} , COMP _{IN} to PC _{OUT}	t _{PHL} , t _{PLH}	C _L = 50pF	4.5	-	-	45	-	56	-	68	ns			
			SIG _{IN} , COMP _{IN} to PCP _{OUT}	t _{PHL} , t _{PLH}	C _L = 50pF	4.5	-	-	68	-	85	-	102	ns
			SIG _{IN} , COMP _{IN} to PC3 _{OUT}	t _{PHL} , t _{PLH}	C _L = 50pF	4.5	-	-	58	-	73	-	87	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns			
Output Enable Time, SIG _{IN} , COMP _{IN} to PC2 _{OUT}	t _{PZH} , t _{PZL}	C _L = 50pF	4.5	-	-	60	-	75	-	90	pF			
Output Disable Time, SIG _{IN} , COMP _{IN} to PCZ _{OUT}	t _{PHZ} , t _{PLZ}	C _L = 50pF	4.5	-	-	68	-	85	-	102	pF			
AC Coupled Input Sensitivity (p-p) at SIG _{IN} or COMP _I		V _{I(P-P)}	4.5	-	15	-	-	-	-	-	mV			
VCO SECTION														
Frequency Stability with Temperature Change	Δf / ΔT	R ₁ = 100kΩ, R ₂ = ∞	4.5	-	0.11	-	-	-	-	-	%/°C			
Maximum Frequency	f _{MAX}	C ₁ = 50pF R ₁ = 3.5kΩ R ₂ = ∞	4.5	-	24	-	-	-	-	-	MHz			
		C ₁ = 0pF R ₁ = 9.1kΩ R ₂ = ∞	4.5	-	38	-	-	-	-	-	MHz			
Center Frequency		C ₁ = 40pF R ₁ = 3kΩ R ₂ = ∞ VCO _{IN} = VCC/2	4.5	12	17	-	-	-	-	-	MHz			
Frequency Linearity	Δf _{VCO}	R ₁ = 100kΩ R ₂ = ∞ C ₁ = 100pF	4.5	-	0.4	-	-	-	-	-	%			

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Switching Specifications $C_L = 50\text{pF}$, Input $t_r, t_f = 6\text{ns}$ (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	V_{CC} (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Offset Frequency		$R_2 = 220\text{k}\Omega$ $C_1 = 1\text{nF}$	4.5	-	400	-	-	-	-	-	kHz
DEMODULATOR SECTION											
$V_{OUT} V_S f_{IN}$		$R_1 = 100\text{k}\Omega$ $R_2 = \infty$ $C_1 = 100\text{pF}$ $R_S = 10\text{k}\Omega$ $R_3 = 100\text{k}\Omega$ $C_2 = 100\text{pF}$	4.5	-	330	-	-	-	-	-	mV/kHz

Test Circuits and Waveforms

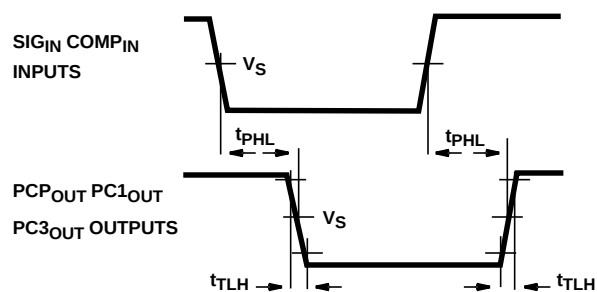


FIGURE 8. INPUT TO OUTPUT PROPAGATION DELAYS AND OUTPUT TRANSITION TIMES

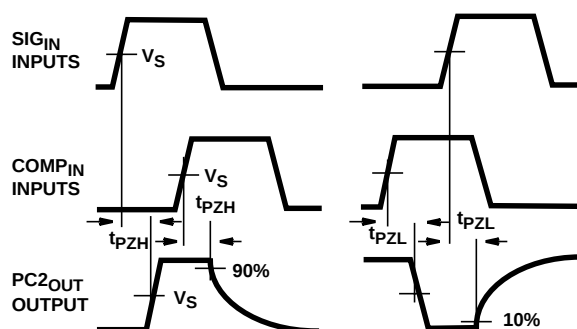


FIGURE 9. THREE STATE ENABLE AND DISABLE TIMES FOR PC2_OUT

Typical Performance Curves

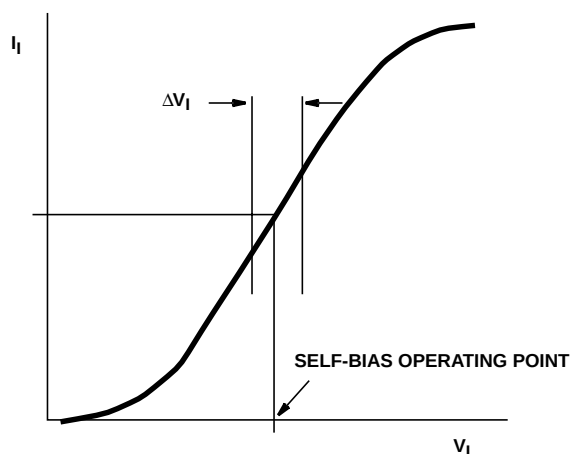


FIGURE 10. TYPICAL INPUT RESISTANCE CURVE AT SIG_IN, COMP_IN

Typical Performance Curves (Continued)

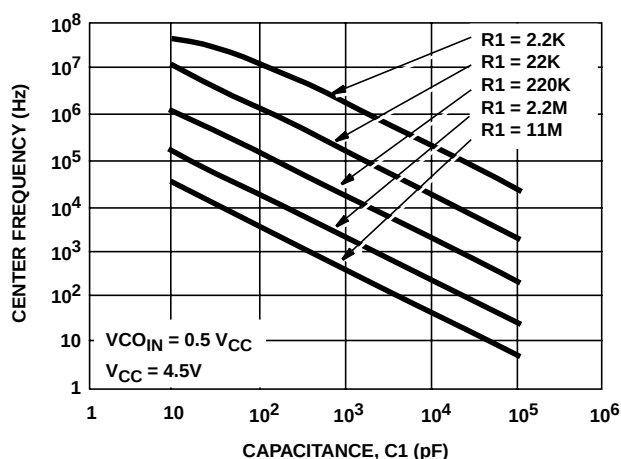


FIGURE 11. HC4046A TYPICAL CENTER FREQUENCY vs R1, C1 ($V_{CC} = 4.5V$)

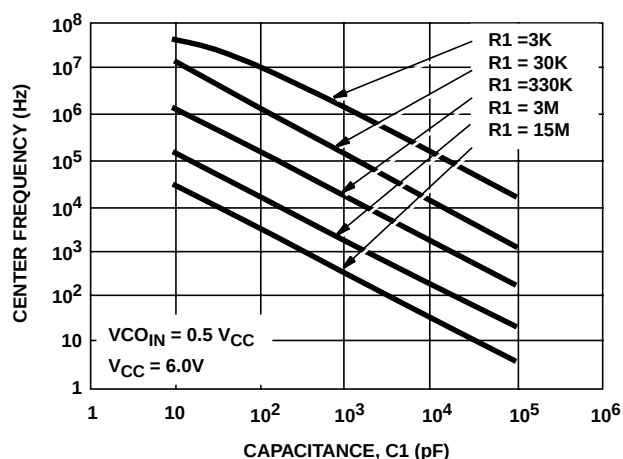


FIGURE 12. HC4046A TYPICAL CENTER FREQUENCY vs R1, C1 ($V_{CC} = 6V$)

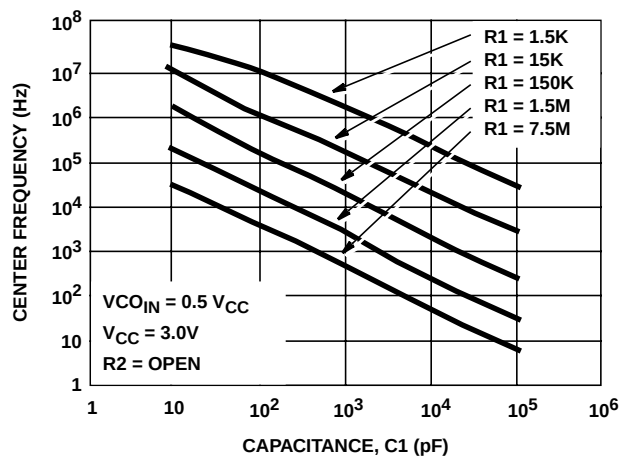


FIGURE 13. HC4046A TYPICAL CENTER FREQUENCY vs R1, C1 ($V_{CC} = 3V$, $R_2 = OPEN$)



FIGURE 14. HCT4046A TYPICAL CENTER FREQUENCY vs R1, C1 ($V_{CC} = 4.5V$)



FIGURE 15. HCT4046A TYPICAL CENTER FREQUENCY vs R1, C1 ($V_{CC} = 5.5V$)



FIGURE 16. HC4046A TYPICAL VCO FREQUENCY vs V_{COIN} ($R_1 = 1.5M\Omega$, $C_1 = 50pF$)

Typical Performance Curves (Continued)



FIGURE 17. HC4046A TYPICAL VCO FREQUENCY vs V_{CO_IN} ($R1 = 1.5M\Omega$, $C1 = 0.1\mu F$)

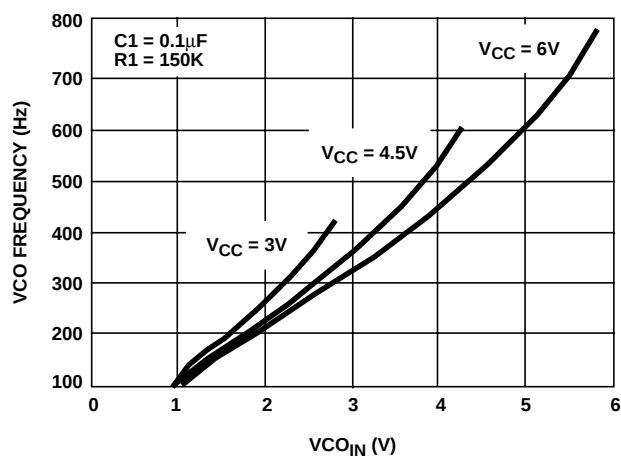


FIGURE 18. HC4046A TYPICAL VCO FREQUENCY vs V_{CO_IN} ($R1 = 150k\Omega$, $C1 = 0.1\mu F$)

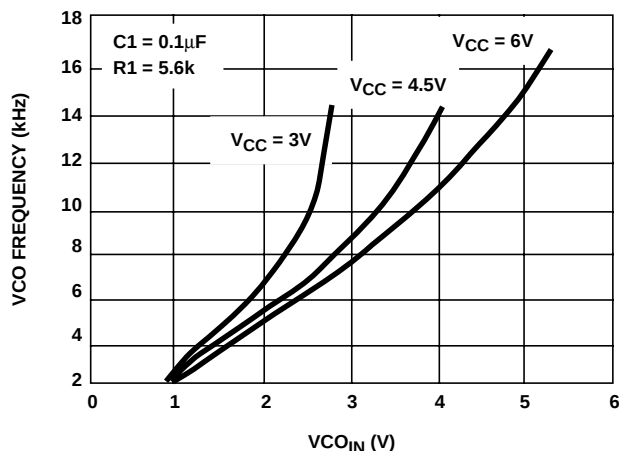


FIGURE 19. HC4046A TYPICAL VCO FREQUENCY vs V_{CO_IN} ($R1 = 5.6k\Omega$, $C1 = 0.1\mu F$)

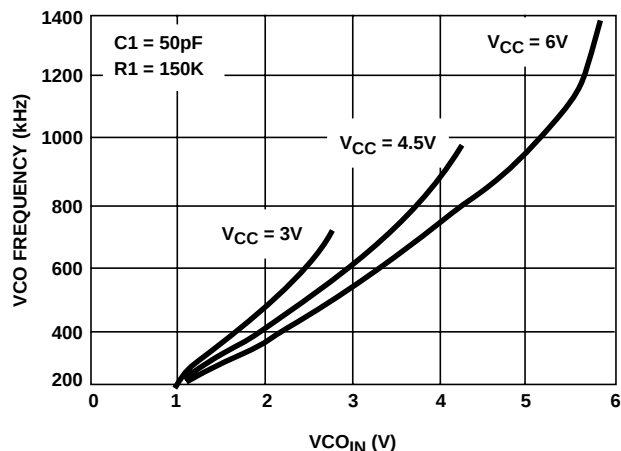


FIGURE 20. HC4046A TYPICAL VCO FREQUENCY vs V_{CO_IN} ($R1 = 150k\Omega$, $C1 = 50pF$)

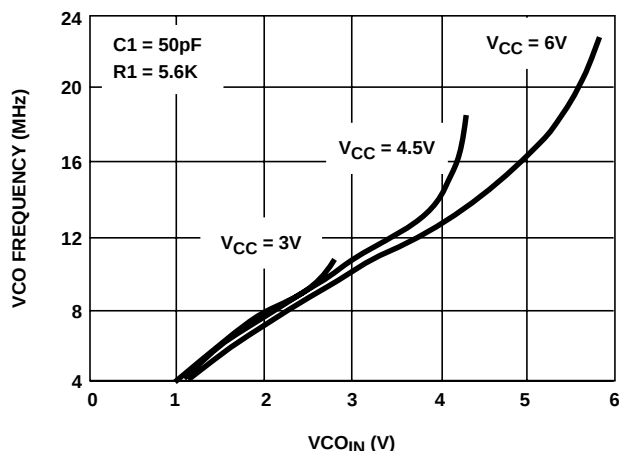


FIGURE 21. HC4046A TYPICAL VCO FREQUENCY vs V_{CO_IN} ($R1 = 5.6k\Omega$, $C1 = 50pF$)

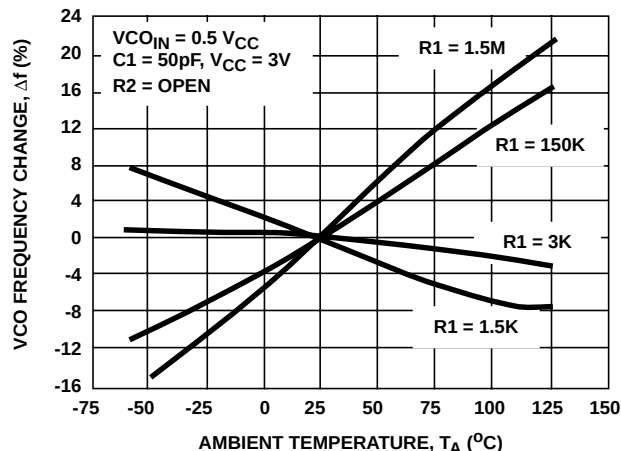


FIGURE 22. HC4046A TYPICAL CHANGE IN VCO FREQUENCY vs AMBIENT TEMPERATURE AS A FUNCTION OF $R1$ ($V_{CC} = 3V$)

Typical Performance Curves (Continued)

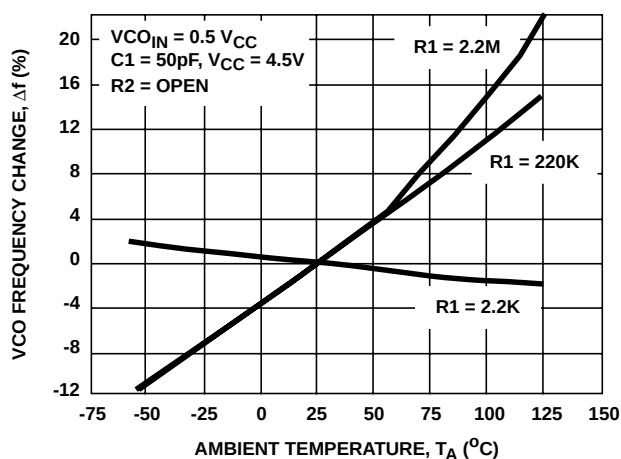


FIGURE 23. HC4046A TYPICAL CHANGE IN VCO FREQUENCY vs AMBIENT TEMPERATURE AS A FUNCTION OF $R1$ ($V_{CC} = 4.5\text{V}$)

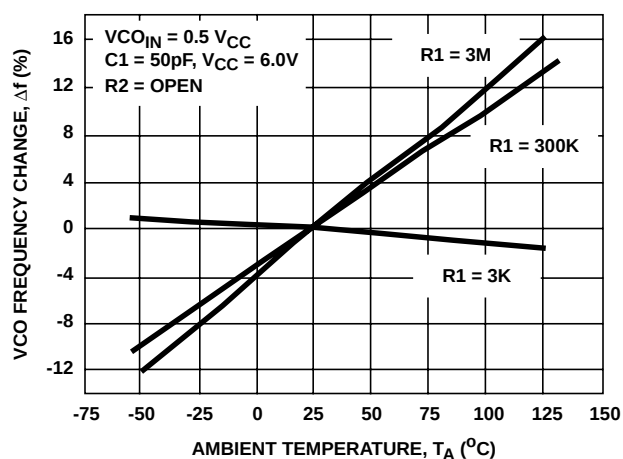


FIGURE 24. HC4046A TYPICAL CHANGE IN VCO FREQUENCY vs AMBIENT TEMPERATURE AS A FUNCTION OF $R1$ ($V_{CC} = 6\text{V}$)

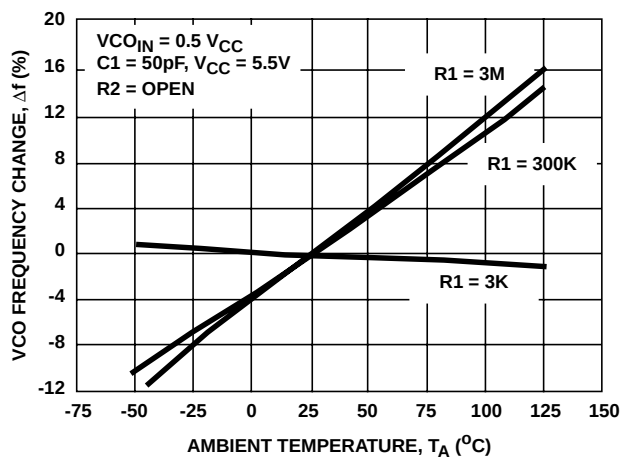


FIGURE 25. HCT4046A TYPICAL CHANGE IN VCO FREQUENCY vs AMBIENT TEMPERATURE AS A FUNCTION OF $R1$

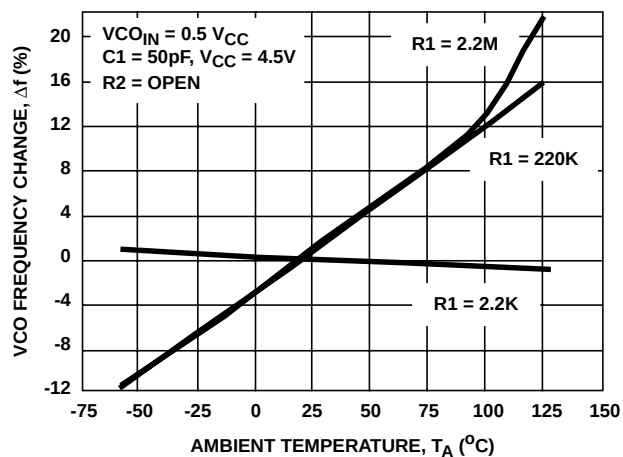


FIGURE 26. HC4046A TYPICAL CHANGE IN VCO FREQUENCY vs AMBIENT TEMPERATURE AS A FUNCTION OF $R1$ ($V_{CC} = 4.5\text{V}$)

Typical Performance Curves (Continued)

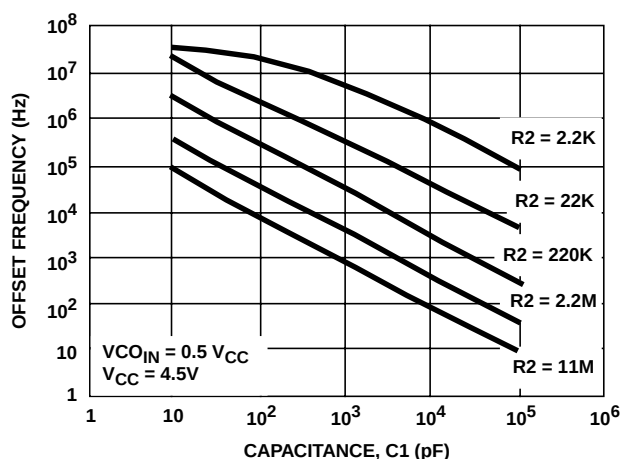


FIGURE 27. HC4046A OFFSET FREQUENCY vs R2, C1 ($V_{CC} = 4.5V$)

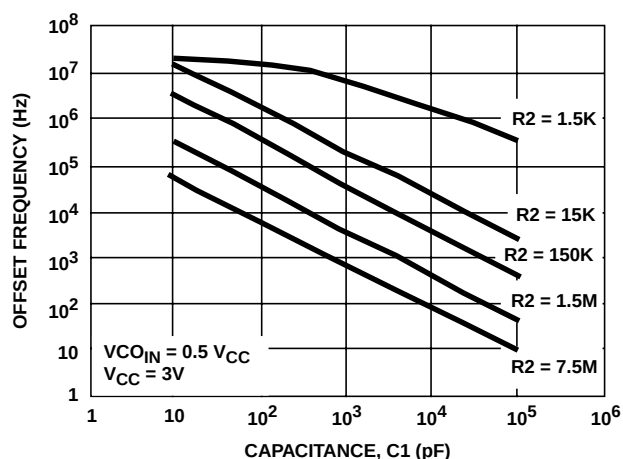


FIGURE 28. HC4046A OFFSET FREQUENCY vs R2, C1 ($V_{CC} = 3V$)



FIGURE 29. HCT4046A OFFSET FREQUENCY vs R2, C1 ($V_{CC} = 4.5V$)

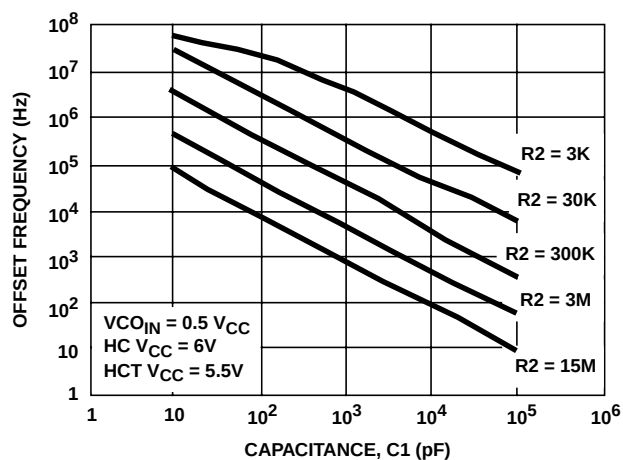


FIGURE 30. HC4046A AND HCT4046A OFFSET FREQUENCY vs R2, C1 ($V_{CC} = 6V$, $V_{CC} = 5.5V$)

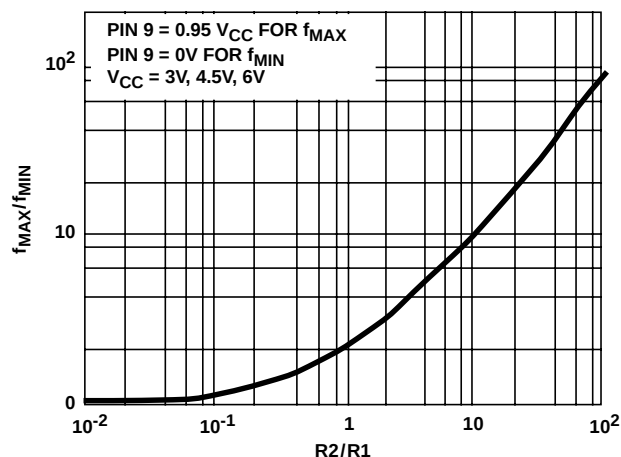


FIGURE 31. HC4046A f_{MIN}/f_{MAX} vs R2/R1 ($V_{CC} = 3V, 4.5V, 6V$)

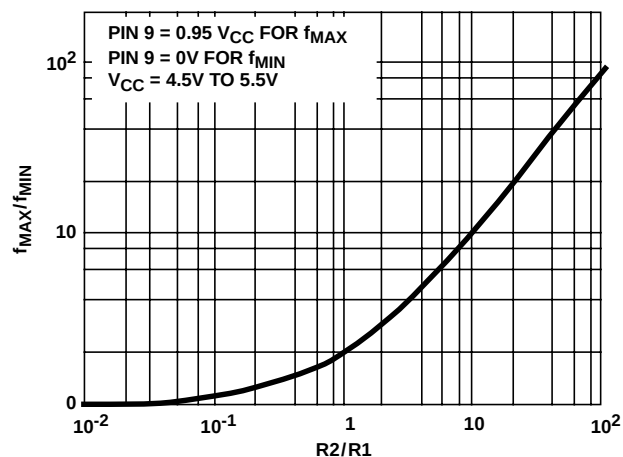


FIGURE 32. HCT4046A f_{MAX}/f_{MIN} vs R2/R1 ($V_{CC} = 4.5V$ TO $5.5V$)

Typical Performance Curves (Continued)



FIGURE 33. DEFINITION OF VCO FREQUENCY LINEARITY



FIGURE 34. HC4046A VCO LINEARITY vs $R1$ ($V_{CC} = 4.5V$)



FIGURE 35. HC4046A VCO LINEARITY vs $R1$ ($V_{CC} = 3V$)



FIGURE 36. HC4046A VCO LINEARITY vs $R1$ ($V_{CC} = 6V$)

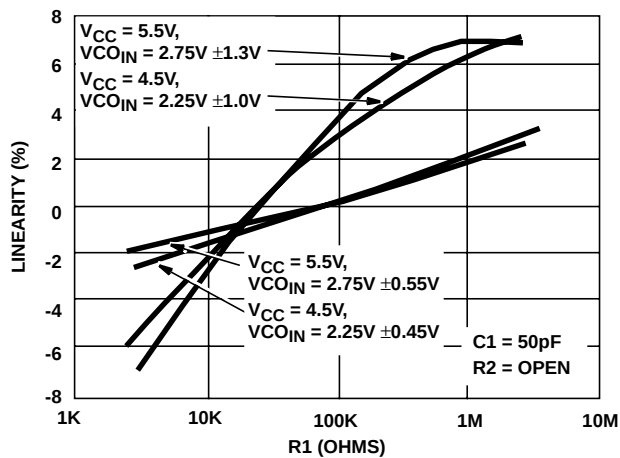


FIGURE 37. HCT4046A VCO LINEARITY vs $R1$ ($V_{CC} = 4.5V$, $V_{CC} = 5.5V$)

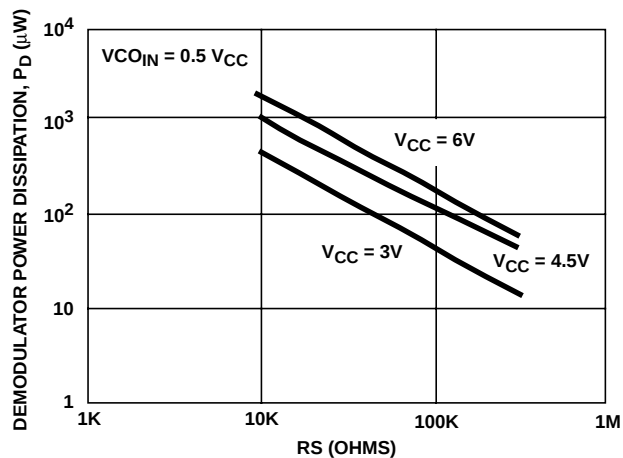


FIGURE 38. HC4046A DEMODULATOR POWER DISSIPATION vs R_S (TYP) ($V_{CC} = 3V, 4.5V, 6V$)

Typical Performance Curves (Continued)

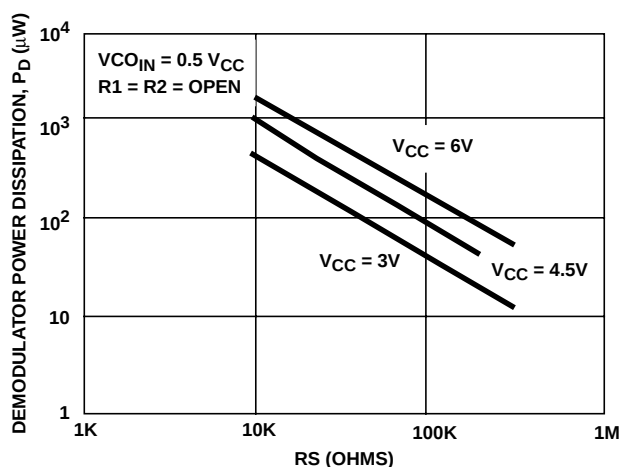


FIGURE 39. HCT4046A DEMODULATOR POWER DISSIPATION vs R_S (TYP) ($V_{CC} = 3V, 4.5V, 6V$)

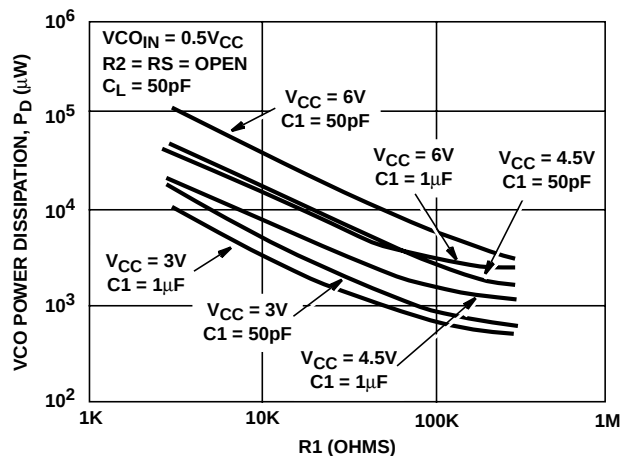


FIGURE 40. HC4046A VCO POWER DISSIPATION vs R_1 ($C_1 = 50pF, 1\mu F$)



FIGURE 41. HCT4046A VCO POWER DISSIPATION vs R_2 ($C_1 = 50pF, 1\mu F$)



FIGURE 42. HCT4046A VCO POWER DISSIPATION vs R_1 ($C_1 = 50pF, 1\mu F$)

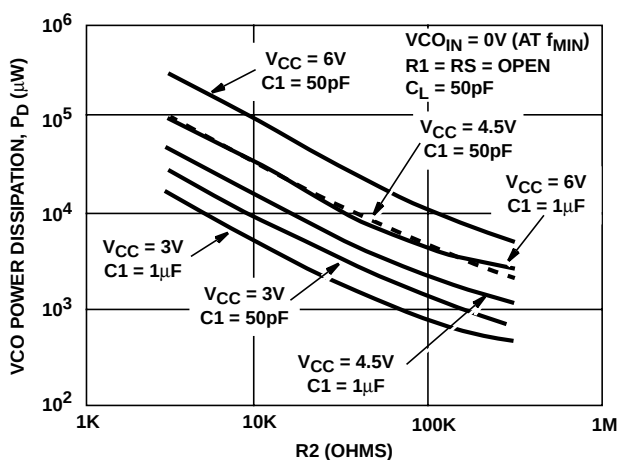


FIGURE 43. HC4046A VCO POWER DISSIPATION vs R_2 ($C_1 = 50pF, 1\mu F$)

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HC/HCT4046A C_{PD}

CHIP SECTION	HC	HCT	UNIT
Comparator 1	48	50	pF
Comparators 2 and 3	39	48	pF
VCO	61	53	pF

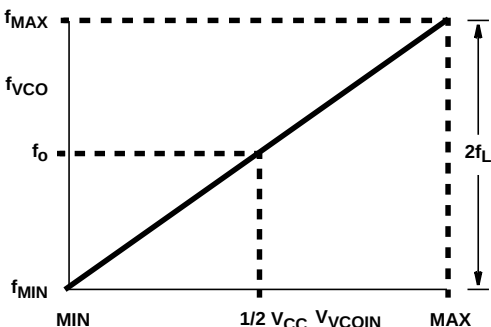
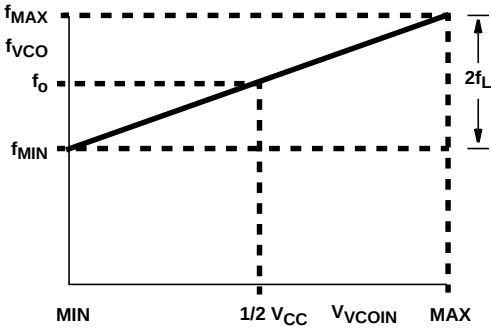
Application Information

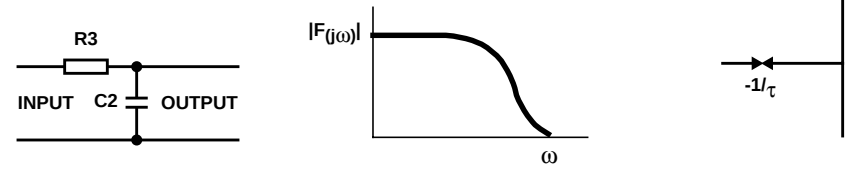
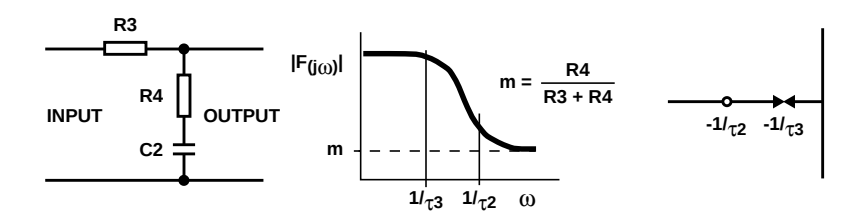
This information is a guide for the approximation of values of external components to be used with the 'HC4046A and 'HCT4046A in a phase-lock-loop system.

References should be made to Figures 11 through 15 and Figures 27 through 32 as indicated in the table.

Values of the selected components should be within the following ranges:

R1	Between 3kΩ and 300kΩ
R2	Between 3kΩ and 300kΩ
R1 + R2	Parallel Value > 2.7kΩ
C1	Greater Than 40pF

SUBJECT	PHASE COMPARATOR	DESIGN CONSIDERATIONS
VCO Frequency Without Extra Offset	PC1, PC2 or PC3	VCO Frequency Characteristic With $R2 = \infty$ and $R1$ within the range $3k\Omega < R1 < 300k\Omega$, the characteristics of the VCO operation will be as shown in Figures 11 - 15. (Due to $R1$, $C1$ time constant a small offset remains when $R2 = \infty$.)  FIGURE 44. FREQUENCY CHARACTERISTIC OF VCO OPERATING WITHOUT OFFSET: f_0 = CENTER FREQUENCY: $2f_L$ = FREQUENCY LOCK RANGE
	PC1	Selection of $R1$ and $C1$ Given f_0, determine the values of $R1$ and $C1$ using Figures 11 - 15
	PC2 or PC3	Given f_{MAX} calculate f_0 as $f_{MAX}/2$ and determine the values of $R1$ and $C1$ using Figures 11 - 15. To obtain $2f_L$: $2f_L \approx 1.2 (V_{CC} - 1.8V)/(R1C1)$ where valid range of V_{COIN} is $1.1V < V_{COIN} < V_{CC} - 0.9V$
VCO Frequency with Extra Offset	PC1, PC2 or PC3	VCO Frequency Characteristic With $R1$ and $R2$ within the ranges $3k\Omega < R1 < 300k\Omega$, $3k\Omega < R2 < 300k\Omega$, the characteristics of the VCO operation will be as shown in Figures 27 - 32.  FIGURE 45. FREQUENCY CHARACTERISTIC OF VCO OPERATING WITH OFFSET: f_0 = CENTER FREQUENCY: $2f_L$ = FREQUENCY LOCK RANGE
	PC1, PC2 or PC3	Selection of $R1$, $R2$ and $C1$ Given f_0 and f_L, offset frequency, f_{MIN}, may be calculated from $f_{MIN} \approx f_0 - 1.6 f_L$. Obtain the values of $C1$ and $R2$ by using Figures 27 - 30. Calculate the values of $R1$ from Figures 31 - 32.

SUBJECT	PHASE COMPARATOR	DESIGN CONSIDERATIONS
PLL Conditions with No Signal at the SIG _{IN} Input	PC1	VCO adjusts to f_0 with $\phi_{\text{DEMOUT}} = 90^\circ$ and $V_{\text{VCOIN}} = 1/2 V_{\text{CC}}$ (see Figure 2)
	PC2	VCO adjusts to f_{MIN} with $\phi_{\text{DEMOUT}} = -360^\circ$ and $V_{\text{VCOIN}} = 0\text{V}$ (see Figure 4)
	PC3	VCO adjusts to f_{MAX} with $\phi_{\text{DEMOUT}} = 360^\circ$ and $V_{\text{VCOIN}} = V_{\text{CC}}$ (see Figure 6)
PLL Frequency Capture Range	PC1, PC2 or PC3	Loop Filter Component Selection  (A) $\tau = R3 \times C2$ (B) AMPLITUDE CHARACTERISTIC (C) POLE-ZERO DIAGRAM A small capture range ($2f_c$) is obtained if $\tau > 2f_c \approx 1/\pi (2\pi f_L/\tau.)^{1/2}$ FIGURE 46. SIMPLE LOOP FILTER FOR PLL WITHOUT OFFSET
		 (A) $\tau_1 = R3 \times C2$; $\tau_2 = R4 \times C2$; $\tau_3 = (R3 + R4) \times C2$ (B) AMPLITUDE CHARACTERISTIC (C) POLE-ZERO DIAGRAM FIGURE 47. SIMPLE LOOP FILTER FOR PLL WITH OFFSET
PLL Locks on Harmonics at Center Frequency	PC1 or PC3	Yes
	PC2	No
Noise Rejection at Signal Input	PC1	High
	PC2 or PC3	Low
AC Ripple Content when PLL is Locked	PC1	$f_r = 2f_i$, large ripple content at $\phi_{\text{DEMOUT}} = 90^\circ$
	PC2	$f_r = f_i$, small ripple content at $\phi_{\text{DEMOUT}} = 0^\circ$
	PC3	$f_r = f_{\text{SIGIN}}$, large ripple content at $\phi_{\text{DEMOUT}} = 180^\circ$

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8875701EA	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8875701EA CD54HCT4046AF3 A	Samples
5962-8960901EA	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8960901EA CD54HC4046AF3A	Samples
CD54HC4046AF	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	CD54HC4046AF	Samples
CD54HC4046AF3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8960901EA CD54HC4046AF3A	Samples
CD54HCT4046AF3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8875701EA CD54HCT4046AF3 A	Samples
CD74HC4046AE	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4046AE	Samples
CD74HC4046AM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4046AM	Samples
CD74HC4046AM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4046AM	Samples
CD74HC4046AM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4046AM	Samples
CD74HC4046AM96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4046AM	Samples
CD74HC4046AMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4046AM	Samples
CD74HC4046AMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4046AM	Samples
CD74HC4046ANSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4046AM	Samples
CD74HC4046ANSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4046AM	Samples
CD74HC4046APWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4046A	Samples
CD74HC4046APWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4046A	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HC4046APWT	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4046A	Samples
CD74HCT4046AE	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4046AE	Samples
CD74HCT4046AEE4	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4046AE	Samples
CD74HCT4046AM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4046AM	Samples
CD74HCT4046AM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4046AM	Samples
CD74HCT4046AM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4046AM	Samples
CD74HCT4046AMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4046AM	Samples
CD74HCT4046AMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4046AM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD54HC4046A, CD54HCT4046A, CD74HC4046A, CD74HCT4046A :

- Catalog: [CD74HC4046A](#), [CD74HCT4046A](#)
- Military: [CD54HC4046A](#), [CD54HCT4046A](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4046AM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4046ANSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC4046APWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4046APWT	TSSOP	PW	16	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HCT4046AM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4046AM96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC4046ANSR	SO	NS	16	2000	367.0	367.0	38.0
CD74HC4046APWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD74HC4046APWT	TSSOP	PW	16	250	367.0	367.0	35.0
CD74HCT4046AM96	SOIC	D	16	2500	333.2	345.9	28.6

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE

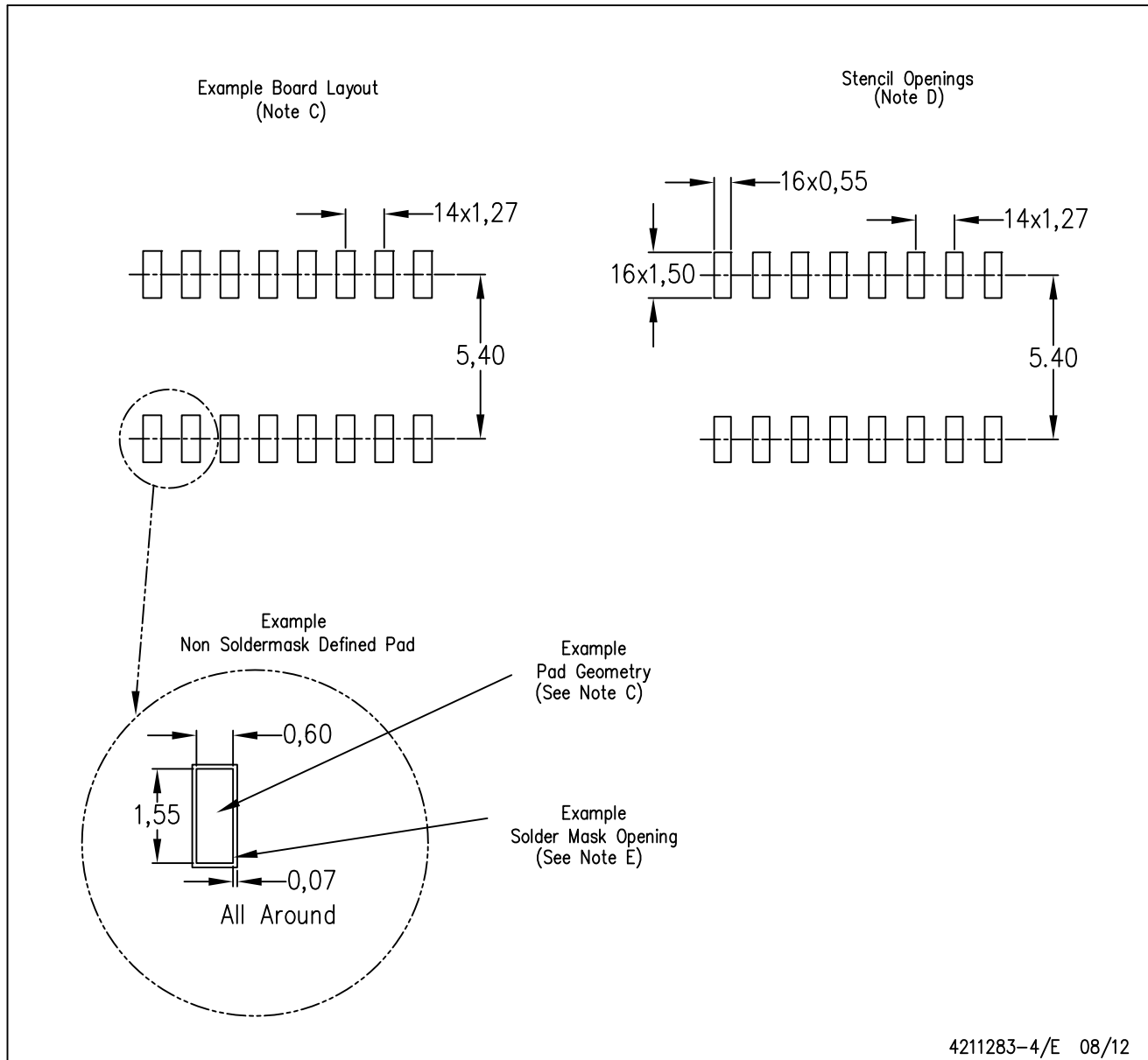


4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



4220204/A 02/2017

NOTES:

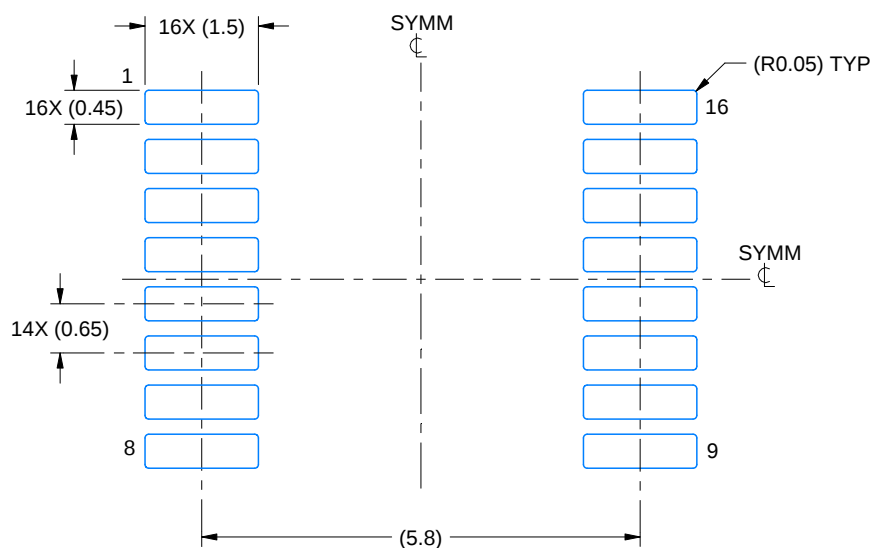
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

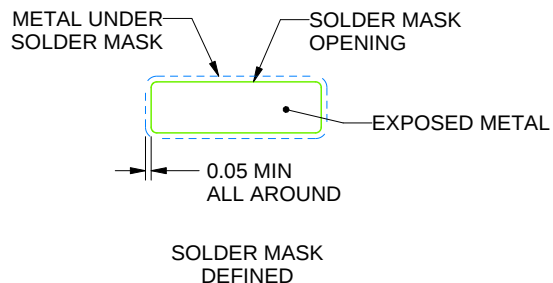
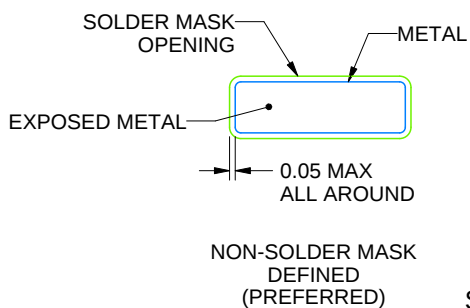
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220204/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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